NSN 5961-00-850-6635

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
0.350 inches
Terminal Length:
0.225 inches
Overall Diameter:
1.350 inches
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
8.2 regulator voltage
Current Rating Per Characteristic:
31.00 milliamperes repetitive peak forward current
Power Rating Per Characteristic:
1.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Terminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
80131-release2986 professional/industrial association specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0